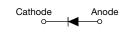


Vishay Semiconductors

Schottky Rectifier, 1 A



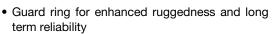


SMA

PRODUCT SUMMARY				
Package	SMA			
I _{F(AV)}	1 A			
V_{R}	100 V			
V _F at I _F	0.63 V			
I _{RM}	1 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	1.0 mJ			

FEATURES

• Low forward voltage drop





• Halogen-free according to IEC 61249-2-21 definition

- HALOGEN FREE
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS directive 2002/95/EC

DESCRIPTION

The VS-10MQ100-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	DC	1	A		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	120	А		
V _F	1.5 Apk, T _J = 125 °C	0.68	V		
T _J	Range	- 55 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10MQ100-M3	UNITS	
Maximum DC reverse voltage	V_{R}	100	V	
Maximum working peak reverse voltage	V_{RWM}	100	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_L = 135 °C On PC board 9 mm ² island (0.013 mm thick copper pad are		1	А
Maximum peak one cycle non-repetitive surge current, T _{.I} = 25 °C		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	120	Α
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.5 \text{A}, L = 8 \text{mH}$		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	Α

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T _{.1} = 25 °C	0.78	V
Maximum forward voltage drop	V _{EM} (1)	1.5 A	11 = 23 0	0.85	
See fig. 1	V FM (1)	1 A	T _J = 125 °C	0.63	
		1.5 A		0.68	
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _R	0.1	mA
See fig. 2		T _J = 125 °C		1	IIIA
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J} \text{ maximum}$ 0.52 78.4		0.52	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	$V_R = 10 V_{DC}$, $T_J = 25 ^{\circ}C$, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{^{(1)}\,}$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
Approximate weight		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	1.	J

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$

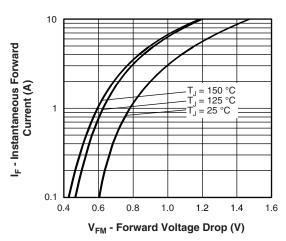


Fig. 1 - Maximum Forward Voltage Drop Characteristics

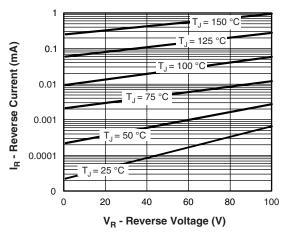


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

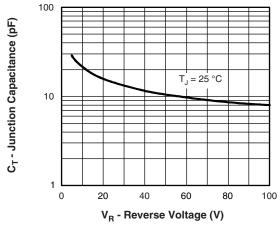
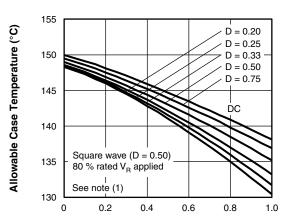
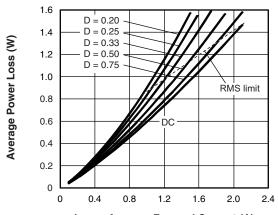


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



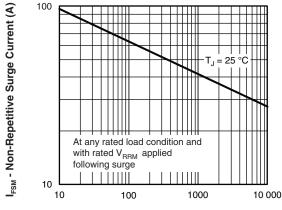
I_{F(AV)} - Average Forward Current (A)

Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature



I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current



t_p - Square Wave Pulse Duration (μs)

Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

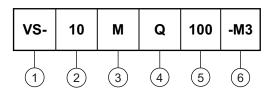
Vishay Semiconductors

Schottky Rectifier, 1 A



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product suffix

2 - Current rating

3 - M = SMA

4 - Q = Schottky "Q" series

5 - Voltage rating (100 = 100 V)

6 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION			
VS-10MQ100-M3/5AT	5AT	7500	13" diameter plastic tape and reel	

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95400</u>				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			

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